

# DMP2077UCA3-7 Datasheet



https://www.DiGi-Electronics.com

DiGi Electronics Part Number DMP2077UCA3-7-DG

Manufacturer Diodes Incorporated

Manufacturer Product Number DMP2077UCA3-7

Description MOSFET P-CH 20V 4A X4-DSN1006-3

Detailed Description P-Channel 20 V 4A (Ta) 660mW Surface Mount X4-D

SN1006-3



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.



# **Purchase and inquiry**

Manufacturer Product Number:	Manufacturer:
DMP2077UCA3-7	Diodes Incorporated
Series:	Product Status:
	Active
FET Type:	Technology:
P-Channel	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss):	Current - Continuous Drain (Id) @ 25°C:
20 V	4A (Ta)
Drive Voltage (Max Rds On, Min Rds On):	Rds On (Max) @ Id, Vgs:
1.5V, 8V	78m0hm @ 500mA, 8V
Vgs(th) (Max) @ ld:	Gate Charge (Qg) (Max) @ Vgs:
1V @ 250μA	1.34 nC @ 4.5 V
Vgs (Max):	Input Capacitance (Ciss) (Max) @ Vds:
±12V	143 pF @ 10 V
FET Feature:	Power Dissipation (Max):
	660mW
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Surface Mount
Supplier Device Package:	Package / Case:
X4-DSN1006-3	3-XFDFN
Base Product Number:	
DMD2077	

# **Environmental & Export classification**

8541.21.0095

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	





#### P-CHANNEL ENHANCEMENT MODE MOSFET

#### **Product Summary**

BV <sub>DSS</sub>	RDS(ON) Max	I <sub>D Max</sub> T <sub>A</sub> = +25°C
-20V	$78m\Omega$ @ $V_{GS} = -8V$	-4.0A
-20V	100mΩ @ $V_{GS} = -4.5V$	-3.5A

#### **Description**

This new generation MOSFET is designed to minimize the footprint in handheld and Mobile application. It can be used to replace many small signals MOSFET with as really small footprint.

#### **Applications**

- Battery Management
- Load Switch
- Battery Protection
- · Handheld and Mobile Application

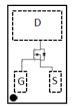
## **Features and Benefits**

- Low Qg & Qgd
- Small Footprint
- Low Profile 0.20mm Height
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

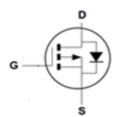
#### **Mechanical Data**

- Case: X4-DSN1006-3
- Terminal Connections: See Diagram Below
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu or NiAu. Solderable per MIL-STD-202, Method 208 (e4)
- Weight: 0.00029 grams (Approximate)





Top View



**Equivalent Circuit** 

#### Ordering Information (Note 4)

Part Number	Case	Packaging
DMP2077UCA3-7	X4-DSN1006-3	10k/Tape & Reel
DMP2077UCA3-7A	X4-DSN1006-3	10k/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

#### **Marking Information**



Q = Product Type Marking Code YM = Date Code Marking Y or  $\overline{Y}$  = Year (ex: H = 2020) M or  $\overline{M}$  = Month (ex: 9 = September)

#### Date Code Key

Year	2018		2020	2021	2022	2023	2024	2025	2026	2027	2028	2029
Code	F		Н	ı	J	K	L	М	N	0	Р	R
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec



# **Maximum Ratings** (@ $T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	V <sub>DSS</sub>	-20	V		
Gate-Source Voltage			Vgss	±12	V
Continuous Drain Current (Note 5) V <sub>GS</sub> = -8V	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	lo	-4.0 -3.2	А
Continuous Drain Current (Note 5) V <sub>GS</sub> = -4.5V	ID	-3.5 -2.8	А		
Pulsed Drain Current (Note 6)			I <sub>DM</sub>	-16	Α

## **Thermal Characteristics**

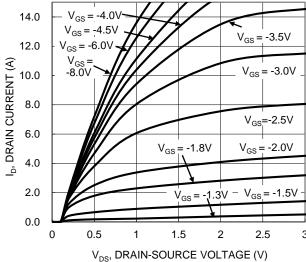
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 7)	PD	0.66	W
Thermal Resistance, Junction to Ambient @T <sub>A</sub> = +25°C (Note 7)	Reja	197	°C/W
Power Dissipation (Note 5)	PD	1.98	W
Thermal Resistance, Junction to Ambient @T <sub>A</sub> = +25°C (Note 5)	Reja	65	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

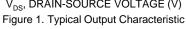
#### Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Tvn	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)	Зуппоп	IVIIII	Тур	IVIAX	Unit	rest condition
Drain-Source Breakdown Voltage	BVpss	-20	_		V	V <sub>G</sub> S = 0V, I <sub>D</sub> = -250μA
Zero Gate Voltage Drain Current T <sub>J</sub> = +25°C	IDSS	_	_	-100	nA	$V_{DS} = -16V, V_{GS} = 0V$
Gate-Source Leakage	Igss			±50	nA	$V_{GS} = 10V, V_{GS} = 0V$ $V_{GS} = \pm 12V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 8)	1633			200	117 (	VGS - ±12V, VDS - 0V
Gate Threshold Voltage	V <sub>GS(TH)</sub>	-0.5	-0.85	-1.0	V	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = -250µA
Cate 1111001101a Voltage	V 00(111)		66	78		$V_{GS} = -8V$ , $I_{D} = -0.5A$
			78	100		VGS = -4.5V, ID = -0.5A
Static Drain-Source On-Resistance	RDS(ON)		112	165	mΩ	VGS = -2.5V, ID = -0.5A
Otalio Diani Godino Giri (Godina	1100(014)		165	600		$V_{GS} = -1.8V, I_{D} = -0.1A$
			295	900		VGS = -1.5V, ID = -0.1A
Diode Forward Voltage	Vsp		-0.73	-1.0	V	$V_{GS} = 0V$ , $I_{S} = -0.5A$
Reverse Recovery Charge	QRR		1.3	_	nC	$V_{DD} = -10V$ , $I_F = -1A$ ,
Reverse Recovery Time	trr		7.7	_	ns	$di/dt = 100A/\mu s$
DYNAMIC CHARACTERISTICS (Note 9)	THE					10.00
Input Capacitance	Ciss	_	143	_		
Output Capacitance	Coss		76	_	pF	$V_{DS} = -10V$ , $V_{GS} = 0V$ ,
Reverse Transfer Capacitance	Crss		3.2	_		f = 1MHz
Series Gate Resistance	Rg		4.7	_	Ω	f = 1MHz, V <sub>G</sub> S = 0V, V <sub>D</sub> S = 0V
Total Gate Charge	Qg		1.34	_		, ,
Gate-Source Charge	Qgs		0.12	_		VGS = -4.5V. VDS = -10V.
Gate-Drain Charge	Q <sub>qd</sub>		0.15	_	nC	I <sub>D</sub> = -0.5A
Gate Charge at VTH	Q <sub>g(TH)</sub>	_	0.24	_		
Turn-On Delay Time	t <sub>D</sub> (ON)		15.4	_		
Turn-On Rise Time	t <sub>R</sub>	_	5.7	_		V <sub>DS</sub> = -10V, V <sub>GS</sub> = -4.5V,
Turn-Off Delay Time	tD(OFF)	_	5.8	_	ns	$R_g = 2\Omega, I_D = -0.5A$
Turn-Off Fall Time	tr	_	5.4	_		

Notes:

<sup>5.</sup> Device mounted on FR-4 material with 1inch² (6.45cm²), 2oz. (0.071mm thick) Cu. 6. Repetitive rating, pulse width limited by junction temperature. 7. Device mounted on FR-4 PCB with minimum recommended pad layout, single sided. 8. Short duration pulse test used to minimize self-heating effect. 9. Guaranteed by design. Not subject to production testing.





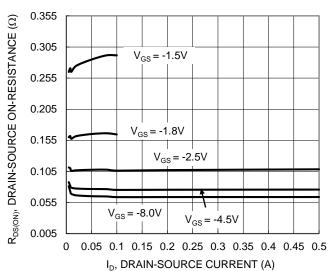


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

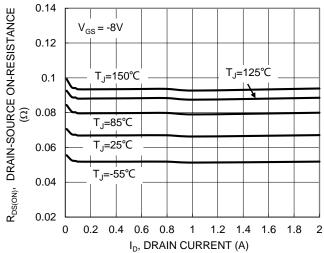
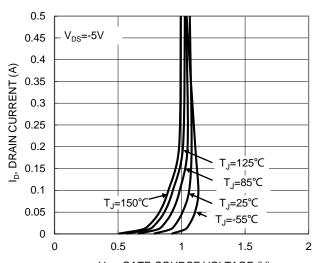


Figure 5. Typical On-Resistance vs. Drain Current and Junction Temperature



 $V_{\text{GS}}$ , GATE-SOURCE VOLTAGE (V) Figure 2. Typical Transfer Characteristic

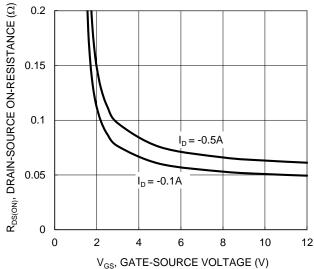


Figure 4. Typical Transfer Characteristic

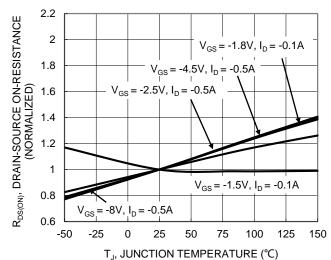


Figure 6. On-Resistance Variation with Junction Temperature



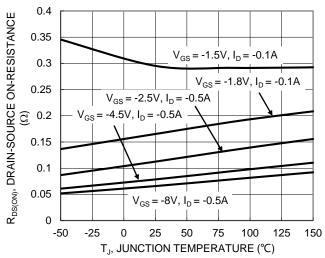
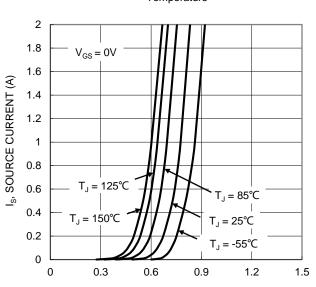


Figure 7. On-Resistance Variation with Junction Temperature



V<sub>SD</sub>, SOURCE-DRAIN VOLTAGE (V) Figure 9. Diode Forward Voltage vs. Current

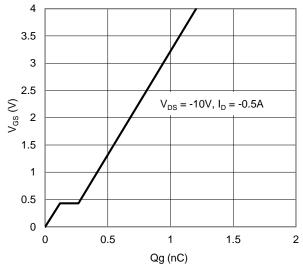


Figure 11. Gate Charge

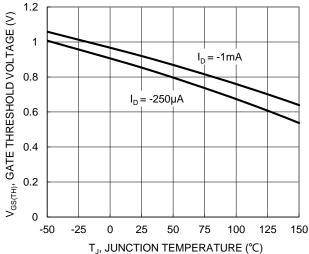


Figure 8. Gate Threshold Variation vs. Junction Temperature

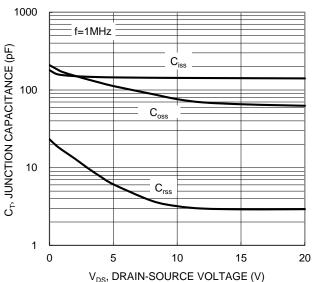


Figure 10. Typical Junction Capacitance

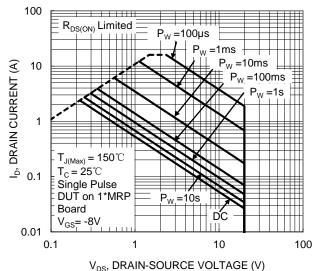


Figure 12. SOA, Safe Operation Area



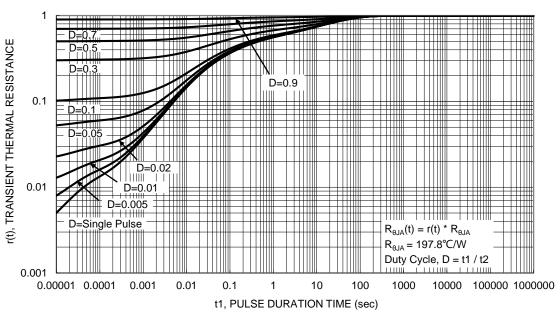


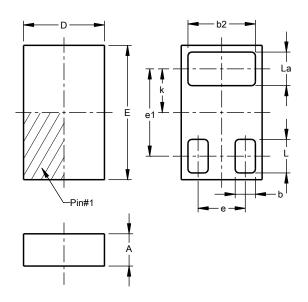
Figure 13. Transient Thermal Resistance



## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### X4-DSN1006-3

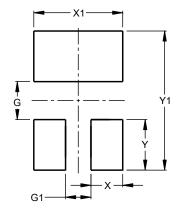


X4-DSN1006-3					
Dim	Min	Max	Тур		
Α	0.18	0.22	0.20		
b	0.14	0.16	0.15		
b2	0.49	0.51	0.50		
D	0.56	0.64	0.60		
Е	0.96	1.04	1.00		
е			0.35		
e1	1	-	0.65		
k			0.325		
L	0.24	0.26	0.25		
La	0.24	0.26	0.25		
All Dimensions in mm					

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### X4-DSN1006-3



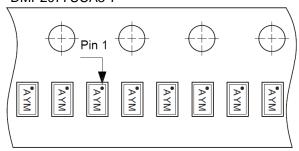
Dimensions	Value (in mm)
G	0.40
G1	0.20
Х	0.15
X1	0.50
Y	0.25
Y1	0.90



## **Tape and Reel Information**

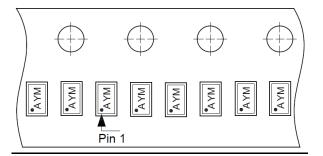
Please see https://www.diodes.com/assets/Packaging-Support-Docs/ap02007.pdf for the latest version.

#### DMP2077UCA3-7



#### DMP2077UCA3-7A

Change the PIN1 orientation in the carrier tape, rotate 180 degrees (Top side).





#### **IMPORTANT NOTICE**

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

#### **LIFE SUPPORT**

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

- A. Life support devices or systems are devices or systems which:
  - 1. are intended to implant into the body, or
  - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2020, Diodes Incorporated

www.diodes.com



# **OUR CERTIFICATE**

DiGi provide top-quality products and perfect service for customer worldwide through standardization, technological innovation and continuous improvement. DiGi through third-party certification, we striciy control the quality of products and services. Welcome your RFQ to Email: Info@DiGi-Electronics.com

















Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com